

SBD30100SCTB、SBDF30100SCTB

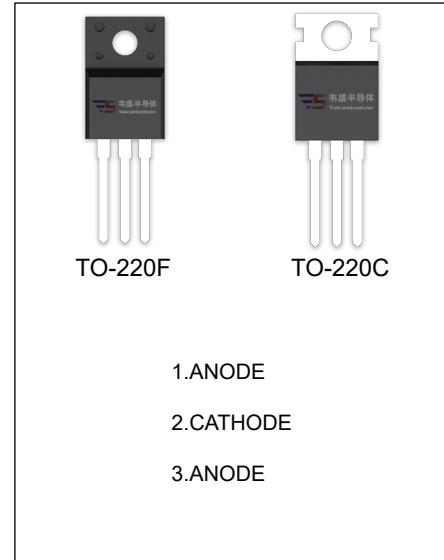
SCHOTTKY BARRIER RECTIFIER

MAIN CHARACTERISTICS

I_o	30 (2×15) A
V_{RRM}	100 V
T_j	150 °C
$V_{F(ty)}$	0.63V (@ $T_j=125^\circ\text{C}$)

FEATURES

- Low Power Loss, High Efficiency
- Guard Ring Die Construction for Transient Protection
- High Current Capability and Low Forward Voltage Drop



MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	SBD		Unit
		30100SCTB	F30100SCTB	
V_{RRM}	Peak repetitive reverse voltage			
V_{RWM}	Working peak reverse voltage		100	V
V_R	DC blocking voltage			
$V_{R(RMS)}$	RMS reverse voltage	70		V
I_o	Average rectified output current	30		A
I_{FSM}	Non-Repetitive peak forward surge current (8.3ms half sine wave)	200		A
$R_{θJC}$	Thermal resistance from junction to case , $T_c=25^\circ\text{C}$	2.0	3.0	°C/W
$R_{θJA}$	Thermal resistance from junction to ambient	62.5		°C/W
T_j	Junction temperature	150		°C
T_{stg}	Storage temperature	-55~+150		°C

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test conditions		Min	Typ	Max	Unit
Reverse voltage	$V_{(BR)}$	$I_R=1\text{mA}$		100			V
Reverse current	I_R	$V_R=100\text{V}$	$T_j = 25^\circ\text{C}$		10	100	uA
			$T_j = 125^\circ\text{C}$		10		mA
Forward voltage	V_F	$I_F=10\text{A}$	$T_j = 25^\circ\text{C}$		0.58		V
			$T_j = 125^\circ\text{C}$		0.56		V
		$I_F=15\text{A}$	$T_j = 25^\circ\text{C}$		0.67	0.71	V
			$T_j = 125^\circ\text{C}$		0.63		V

*Pulse test: pulse width ≤300μs, duty cycle≤ 2.0%.

FIG.1: FORWARD CURRENT DERATING CURVE

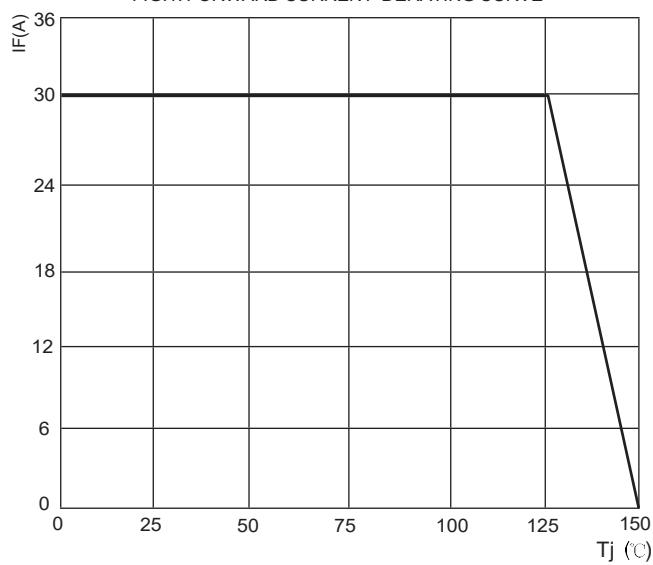


FIG.2: TYPICAL FORWARD CHARACTERISTICS

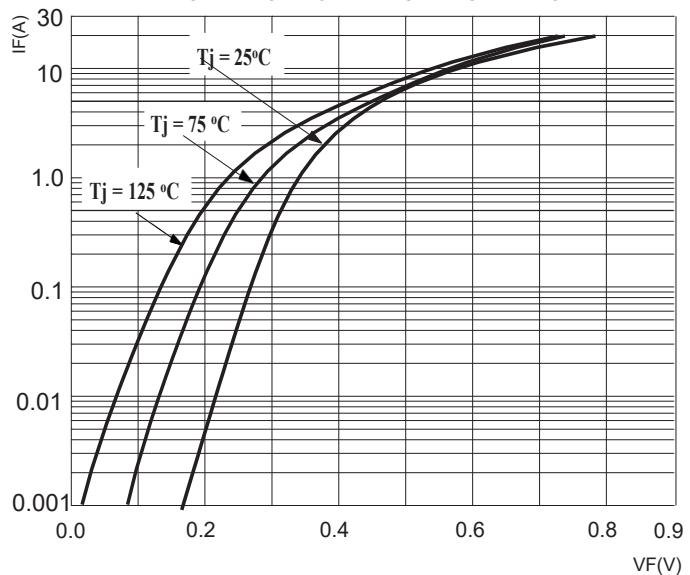


FIG.3: TOTAL CAPACITANCE DERATING CURVE

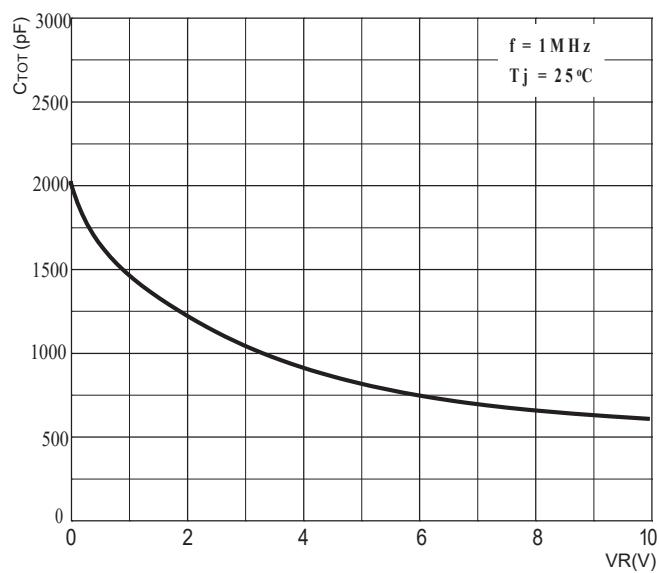


FIG.4: TYPICAL REVERSE CHARACTERISTICS

